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Revealing the Empty-State Electronic Structure of Single-Unit-Cell FeSe/SrTiO$_3$

Dennis Huang,¹ Can-Li Song,¹,† Tatiana A. Webb,¹,² Shiang Fang,¹ Cui-Zu Chang,³ Jagadeesh S. Moodera,³,⁴ Efthimios Kaxiras,¹,⁵ and Jennifer E. Hoffman¹,†

¹Department of Physics, Harvard University, Cambridge, Massachusetts 02139, USA
²Department of Physics and Astronomy, University of British Columbia, Vancouver, British Columbia V6T 1Z1, Canada
³Francis Bitter Magnet Laboratory, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA
⁴Department of Physics, Massachusetts Institute of Technology, Cambridge, Massachusetts 02139, USA
⁵School of Engineering and Applied Sciences, Harvard University, Cambridge, Massachusetts 02138, USA

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We use scanning tunneling spectroscopy to investigate the filled and empty electronic states of superconducting single-unit-cell FeSe deposited on SrTiO$_3$(001). We map the momentum-space band structure by combining quasiparticle interference imaging with decay length spectroscopy. In addition to quantifying the filled-state bands, we discover a $\Gamma$-centered electron pocket 75 meV above the Fermi energy. Our density functional theory calculations show the orbital nature of empty states at $\Gamma$ and explain how the Se height is a key tuning parameter of their energies, with broad implications for electronic properties.

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The extraordinary potential of interface engineering to generate novel electronic properties is exemplified by a single unit cell (1UC) of FeSe deposited on SrTiO$_3$ [1], which exhibits an order-of-magnitude increase in its superconducting transition temperature ($T_c$ up to 110 K [2]) compared to bulk FeSe ($T_c = 9.4$ K [3]). Not only does this finding elevate the $T_c$ of iron-based superconductors (Fe-SCs) above the liquid nitrogen temperature, it also opens the door to designing Fe-SC/oxide heterostructures with novel phases and yet higher $T_c$. A key to understanding and realizing these phases is a complete measurement of the electronic structure of filled and empty states.

Electronic band structure is pivotal in determining the pairing symmetry of Fe-SCs. The generic Fermi surface of Fe-SCs consists of electron pockets at the Brillouin zone (BZ) corner $M$ and hole pockets at the zone center $\Gamma$ [4]. A prevalent spin-fluctuation model suggests that repulsive antiferromagnetic excitations of wave vector ($\pi, \pi$) can give rise to pairing between the electron and hole pockets if the order parameter reverses sign, resulting in $s_{+-}$ superconductivity [5,6]. However, in 1UC FeSe/SrTiO$_3$, the $\Gamma$ hole pocket sinks entirely below the Fermi energy ($E_F$) due to electron doping [7]. This challenges the $s_{+-}$ picture; nevertheless, functional renormalization group (FRG) calculations have shown that electronic bands lying within the spin fluctuation energy scale below $E_F$ can still influence the pairing channel. In fact, the energy of the sunken $\Gamma$ hole pocket is predicted to toggle the relative stability between sign-preserving $s_{++}$ and sign-changing $d$ pairing symmetries [8,9].

A natural question is whether low-lying bands above $E_F$ can similarly renormalize the effective interaction. In general, the landscape of empty states in Fe-SCs remains largely unexplored by experiment. A full band structure mapping is particularly crucial in 1UC FeSe/SrTiO$_3$, where in addition to the usual Coulomb repulsion and spin fluctuations, even higher energy phonon modes may be at play [9–11], and the magnitudes of their energy scales relative to the near-$E_F$ bands determine the superconducting ground state.

Here we map the multiband electronic structure of 1UC FeSe/SrTiO$_3$ by two complimentary scanning tunneling microscopy (STM) techniques: (1) quasiparticle interference (QPI) imaging [12] and (2) decay length spectroscopy [13]. In the first technique, impurity scattering of quasi-particles generates interference patterns with characteristic dispersive wave vectors $q(\omega)$ that can be inverted to reconstruct the band structure. Since $q$ is the momentum transfer, QPI imaging resolves only relative momentum coordinates between two states. In the second technique, the absolute, in-plane momentum $k_{\parallel}$ of quasi-particles can be extracted from the decay of their tunneling current with increasing sample-tip separation. By combining the two momentum-resolved techniques, we discover a $\Gamma$ electron pocket 75 meV above $E_F$. Our density functional theory (DFT) calculations reproduce the presence of empty states at $\Gamma$, and furthermore explain how their energies are tuned by the Se height $h_{Se}$.

We grew films of FeSe on Nb-doped SrTiO$_3$(001) (0.5%) via molecular beam epitaxy (MBE). The substrates were pretreated with deionized water for 90 min at 80 °C, followed by an O$_2$ anneal for 3 h at 1000 °C. We then transferred the substrates into our MBE chamber (base pressure $1 \times 10^{-10}$ Torr) and degassed them at 670 °C. We deposited FeSe by coevaporating Fe (99.995%) and
Se (99.999%) with a molar flux ratio of 1:6 and substrate temperature 520 °C. Afterwards, we typically annealed the samples for an additional 2 h between 500–600 °C before transferring them through ultrahigh vacuum to a homebuilt STM for imaging at ~4.3 K.

Figure 1(a) shows a typical film topography, with regions of bare SrTiO$_3$ and 1UC or 2UC of FeSe. We discriminate these regions based on their terrace heights. From the line cut in Fig. 1(b), we observe a 3UC SrTiO$_3$ step to be 1.19 ± 0.05 nm (bulk c-axis lattice constant is 0.3905 nm [14]), the 1–2UC FeSe step to be 0.57 ± 0.05 nm, and the bare SrTiO$_3$–1UC FeSe step to be 0.34 ± 0.02 nm (all measured at 4 V sample-tip bias). We will hereafter focus on the 1UC FeSe terrace. Figure 1(c) presents an atomically resolved topography of 1UC FeSe, with lattice constant $a = 3.9$ Å. Each bright spot corresponds to a surface Se atom in a Se-Fe-Se triple layer. A representative $dI/dV$ spectrum on a clean area exhibits a gap of $\Delta = 14$ meV [Fig. 1(d)], similar in magnitude to other reports of superconducting gaps in this material [7,15]. We note appreciable spectral inhomogeneity in 1UC FeSe/SrTiO$_3$, but further study is needed to quantify its correlation with substrate disorder.

To image QPI, we acquired conductance maps $g(\mathbf{r}, \omega) = dI/dV(\mathbf{r}, eV)$ over flat regions of 1UC FeSe/SrTiO$_3$ with moderate concentrations of as-grown defects [Fig. 2(a)]. Several energy maps of one representative region are presented in Figs. 2(b)–2(e), displaying clearly dispersive interference patterns. To identify the momentum-space origin of the scattered quasiparticles, we compared the Fourier transform amplitudes $|g(\mathbf{q}, \omega)|$ to simulated autocorrelations of the spectral function $A(\mathbf{k}, \omega) = -(1/\pi)\sum_\alpha \text{Im}[G_\alpha(\mathbf{k}, \omega)]$ [17]. For simplicity, we used the bare Green’s function $G^{-1}_\alpha(\mathbf{k}, \omega) = \omega + i\delta - \varepsilon_\alpha(\mathbf{k})$, with parabolic bands $\varepsilon_\alpha(\mathbf{k})$ and broadening $\delta = 5$ meV. The main result is presented in Figs. 3(a)–3(i), which compare $|g(\mathbf{q}, \omega)|$ to theoretical predictions for three representative energies. We discuss each in turn.

$\omega = 10$ meV, Figs. 3(b), 3(e), and 3(h): Close to $E_F$, we observe nine ringlike intensities in $|g(\mathbf{q}, \omega)|$, centered about reciprocal lattice vectors $\mathbf{G} = (0,0), (\pm 2\pi/a, 0), (0, \pm 2\pi/a), \text{and } (\pm 2\pi/a, \pm 2\pi/a)$. These intensities arise from scattering, modulo $\mathbf{G}$, within electron Fermi pockets at the zone corner $M$ (labeled 1 in Fig. 3) [7].

$\omega = -66$ meV, Figs. 3(c), 3(f), and 3(i): Sufficiently below $E_F$, we observe additional scattering channels pointing to the emergence of the $\Gamma$ hole pocket seen by angle-resolved photoemission spectroscopy [7]. Intrapocket scattering between $\Gamma$ pockets is labeled 2 in Fig. 3, while interpocket scattering between $\Gamma$ and $M$ pockets is labeled 1–2 in Fig. 3.

$\omega = 80$ meV, Figs. 3(a), 3(d), and 3(g): Above $E_F$, we discover a third pocket. Intrapocket scattering (labeled 3 in Fig. 3) is clearly resolved in $|g(\mathbf{q}, \omega)|$, but interpocket scattering with the $M$ electron pockets [expected intensity at $(\pi/a, \pi/a)$ modulo $\mathbf{G}$] appears to be suppressed. In general, the autocorrelation of $A(\mathbf{k}, \omega)$ yields the set of all possible scattering channels, but more complex theories that encode spin [18] or orbital [19] selectivity in the scattering $T$ matrix are needed to explain their relative intensities. In this case, the empirical suppression of $\Gamma$-$M$ scattering leaves some ambiguity as to the absolute momentum $(\mathbf{k})$ location of the new pocket.
To visualize the full QPI evolution, Fig. 3(j) shows an azimuthally averaged intensity plot of \( |g(q_r, \omega)| \), where \( q_r \) is measured relative to \( G = (2\pi/a, 0) \) as shown in Fig. 3(h). In total, we observe three dispersing branches: two electronlike (labeled 1 and 3) and one holelike (labeled 2). Branches 1 and 2 correspond to a \( \Gamma \) electron pocket and a \( \Gamma \) hole pocket, while branch 3 awaits further identification. A parabolic fit to branch 1 over the given energy range in Fig. 3(j) yields an effective mass enhancement \( m^*/m = 2.0 \pm 0.1 \) and a carrier concentration of 0.08 e\(^{-}\) per Fe from a Luttinger count, assuming a degenerate pocket [7,20].

To determine the absolute momentum \( k \) of QPI branch 3, a complimentary momentum-resolved STM technique is needed. Here we utilize decay length spectroscopy [13,21,23], a general tool which allows the full reconstruction of \( k \)-space band structure from STM. Tersoff and Hamman [24] showed that a sample state of in-plane momentum \( k_\parallel \) has density which decays towards the vacuum with length \( \lambda \) given by

\[
\frac{1}{(2\lambda)^2} = \frac{2m\Phi}{\hbar^2} + k_\parallel^2,
\]

where \( \Phi \) is the average of the sample and tip work functions. Figures 4(a) and 4(b) show the energy dependent decay length \( \lambda(\omega) \), extracted from exponential fits to the tunneling current as the sample-tip distance is increased at a fixed bias. Near \( E_F \), the sample states have large momentum near \( M \) and smaller decay length. Below \( E_F \), a steep increase in \( \lambda(\omega) \) accompanies the onset of a hole pocket at \( \Gamma \), as states with low momentum become available for tunneling. The fact that a similar rise in \( \lambda(\omega) \) occurs above \( E_F \) indicates that branch 3 in Fig. 3(j) is also located at \( \Gamma \). If we interpret the large-\( |\omega| \) value of \( \lambda = 0.462 \pm 0.001 \) Å as arising from states with \( k \approx 0 \), we find \( \Phi = 4.46 \pm 0.03 \) eV from Eq. (1), then we can compute the
FIG. 5 (color online). (a) Band structure of free-standing single-unit-cell (1UC) FeSe, calculated in the generalized gradient approximation (GGA). Structural parameters: lattice constant $a = 3.90$ Å, Se height $h_{\text{Se}} = 1.45$ Å. (b) Energies of the five $\Gamma$ bands shown in (a) vs $h_{\text{Se}}$ (the band represented by orange is degenerate). The GGA values of $h_{\text{Se}}$ for 1UC FeSe ($a = 3.90$ Å fixed) and bulk FeSe ($a = 3.68$ Å relaxed) are marked, as well as the experimental value for bulk FeSe. The Fermi energy $E_F$ expected from electron doping is marked in (a),(b). (c) Charge density isosurfaces (yellow) at $k = 0$ for the five $\Gamma$ bands, shown in two perspectives. The histograms depict the orbital compositions.

The expected $\lambda(\omega) = 0.318 \pm 0.001$ Å for energies where the only states come from momenta near $M$. Indeed, the measured $\lambda(\omega)$ at small $|\omega|$ closely matches the expected value of $\lambda(\omega) = 2\pi a$. Steplike features associated with the onsets of these pockets are also detected with $dI/dV$ spectroscopy [Fig. 4(c)]. From extrema in the numerical derivative $d^2I/dV^2$, which closely match those of $d\lambda/d\omega$ [vertical shaded guides in Figs. 4(b) and 4(c)], the band edges of the $\Gamma$ hole and electron pockets are $-65$ and $75$ meV.

A consistent band structure for 1UC FeSe/SrTiO$_3$ is now established, comprising $M$ electron pockets spanning $E_F$ and $\Gamma$ hole and electron pockets lying below and above $E_F$. For further insight, we use DFT to compute the band structure of free-standing 1UC FeSe via the generalized gradient approximation (GGA) [25] and projector augmented wave method as implemented in the Vienna $ab$ initio simulation package (VASP) [26,27]. We use a BZ sampling of $9 \times 9 \times 1$ and an energy cutoff of 450 eV. We apply Methfessel-Paxton smearing [28] with $\sigma = 0.1$ eV. Figure 5(a) shows the calculated bands with structural parameters $a = 3.90$ Å, $h_{\text{Se}} = 1.45$ Å. Because of electron doping, $E_F$ should be adjusted to intersect only the $M$ pockets. Typical band renormalization factors range from 4 to 5 in 1UC FeSe/SrTiO$_3$ [29], but for the qualitative discussion that follows, we do not rescale the bands.

Experimentally, $h_{\text{Se}}$ is unknown. Simulations show that the binding geometry of 1UC FeSe/SrTiO$_3$ varies with Ti$_2$O$_3$ oxygen deficiency, which creates electropositive sites that distort Se positions [30]. Without microscopic knowledge of the buried interface, we calculate band structures for a range of $h_{\text{Se}}$ values and track the energies of the $\Gamma$ bands [Fig. 5(b)]. While all bands shift slightly, the lowest-lying $\Gamma$ electron pocket in Fig. 5(a) undergoes a pronounced monotonic decrease in energy with increasing $h_{\text{Se}}$. Figure 5(c) shows the charge density isosurfaces at $k = 0$ and orbital compositions for each band. Only the lowest-lying $\Gamma$ electron pocket carries significant Se $4p$ character in addition to Fe $3d$ character, so it is most affected by the Fe-Se distances. The charge density plot suggests an antibonding configuration of Fe $3d_{x^2-y^2}$ and Se $4p_z$ orbitals, which explains the increase in pocket energy with greater overlap of Fe and Se states. Our calculation reveals a crucial connection between $h_{\text{Se}}$ and empty electronic states.

Previous reports have predicted that Se/Te heights tune the Fe exchange constants in iron chalcogenides and hence the magnetic order [31], which is oddly absent in FeSe [32] and unknown in 1UC FeSe/SrTiO$_3$. Here, we discuss another implication of $h_{\text{Se}}$. As seen in Fig. 5(b), the $\Gamma$ electron and hole pockets cross at large values of $h_{\text{Se}}$. Recently, Wu et al. have proposed that nontrivial $Z_2$ topology may be realized in 1UC FeTe$_{1-x}$Se$_x$ [33]. In particular, when the gap $\Delta_n$ between the $\Gamma$ electron and hole pockets falls below 80 meV, spin-orbit coupling can invert the bands. We measure $\Delta_n$ to be 140 meV from Fig. 4(c); thus, 1UC FeSe/SrTiO$_3$ could possibly lie in proximity to a topological phase transition.

In summary, we have quantified both the filled and empty state band structure of 1UC FeSe/SrTiO$_3$, and discovered a new $\Gamma$-centered pocket emerging around $75$ meV above the Fermi level. Our work has several important implications, both for superconductivity and for predicted topological order in FeSe/SrTiO$_3$. First, the new $\Gamma$ band will serve as an essential input for revised FRG calculations of the effective low-energy pairing interaction [9]. Second, the modest $140$ meV gap we measured between filled and empty Gamma bands gives hope that inversion of these bands may be achievable, and may lead to a predicted topological phase [33]. Finally, our work introduces decay length spectroscopy as a general and complementary technique to QPI imaging, to map the absolute momentum-resolved electronic band structure of filled and empty states using STM. We suggest the use of these techniques in concert to track the $\Gamma$ pocket energies in future strain engineering experiments with FeSe.

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Present address: State Key Laboratory of Low-Dimensional Quantum Physics, Department of Physics, Tsinghua University, Beijing 100084, China

\[\text{jhoffman@physics.harvard.edu}\]


[20] See Supplemental Material at http://link.aps.org/supplemental/10.1103/PhysRevLett.115.017002, which includes Refs. [7,17,21,22], for details pertaining to Fig. 3(j) and quantification of band parameters.


